



### COMMERCIAL SENSITIVE TO-5 RELAYS DPDT



SERIES	RELAY TYPE	
732	DPDT basic relay	
732D	DPDT relay with internal diode for coil transient suppression	
732TN	DPDT relay with internal transistor driver and coil transient suppression diode	

### **DESCRIPTION**

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, the Series 732 relays are some of the most versatile ultraminiature relays available because of their small size and low coil power dissipation.

The following unique construction features and manufacturing techniques provide excellent resistance to environmental extremes and overall high reliability:

#### The 732 feature:

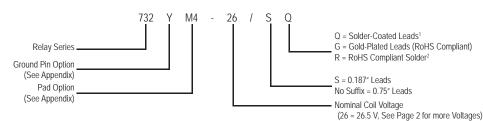
- •All welded construction.
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity.
- High force/mass ratios for resistance to shock and vibration.

- Advanced cleaning techniques provide maximum assurance of internal cleanliness.
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities.

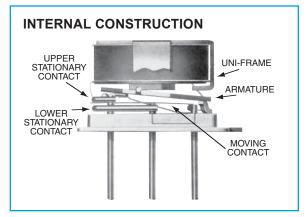
The Series 732D relay has an internal discrete silicon diode for coil transient suppression. The hybrid Series 732TN relay has an internal silicon diode and transistor driver. The integrated packaging of the relay with its associated semiconductor devices greatly reduces PC board floor space requirements as well as component installation costs.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the 732 has proven to be excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the TO-5 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of Transmit-Receive switching

### Part Numbering System



ENVIRONMENTAL AND PHYSICAL SPECIFICATIONS				
Temperature (Ambient)	–65°C to +125°C			
Vibration (General Note I)	10 g's to 500 Hz			
Shock (General Note I)	30 g's, 6ms half sine			
Enclosure	Hermetically sealed			
Weight	0.09 oz. (2.55g) max.			



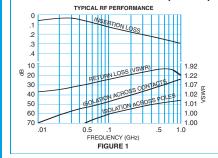


### **SERIES 732** GENERAL ELECTRICAL SPECIFICATIONS (@25°C)

Rated Duty       Continuous         Contact Resistance       0.15 Ω max.; 0.25 Ω max. afterlife at A / 28 Vdc         Contact Load Rating (DC)       Resistive: 200 mA/ 28 Vdc (320mH)	SERVICE LELIS FRANCE OF LOW TO KNOW (@ 10-0)						
Contact Resistance       0.15 Ω max.; 0.25 Ω max. afterlife at A / 28 Vdc         Contact Load Rating (DC)       Resistive: 1 A / 28 Vdc (320mH) (100 mA / 28 Vdc (320mH) (280mH)	Contact Arrangement	2 Form C (DPDT)					
Resistive: 1 A / 28 Vdc   Inductive: 200 mA / 28 Vdc (320mH)   Lamp: 100 mA / 28 Vdc (320mH)   Lamp: 100 mA / 28 Vdc (320mH)   Low level: 10 to 50 μA @ 10 to 50 mV	Rated Duty	Continuous					
Contact Load Rating (DC)       Inductive: Lamp: 100 mA / 28 Vdc (320mH) Low level: 10 to 50 μA @ 10 to 50 mV         Contact Load Rating (AC)       Resistive: 250 mA / 115Vac, 60 and 400 Hz (Case not grounded) 100 mA / 115 Vac, 60 and 400 Hz (Case grounded)         Contact Life Ratings       10,000,000 cycles (typical) at low level 1,000,000 cycles (typical) at 0.5 A / 28 Vdc resistive 100,000 cycles min. at all other loads specified above         Contact Overload Rating       2 A / 28 Vdc Resistive (100 cycles min.)         Coil Operating Power       200 mW typical at nominal rated voltage         Contact Carry Rating       Contact Factory         Operate Time       6.0 msec max. at nominal rated coil voltage         Release Time       732: 3.0 ms max.       732D, 732TN: 7.5 ms max.         Intercontact Capacitance       0.4 pf typical         Insulation Resistance       1,000 MΩ min. between mutually isolated terminals         Dielectric Strength       350 Vrms (60 Hz) @ atmospheric pressure         Negative Coil Transient (Vdc)       2.0 Vdc Max.         Diode P.I.V. (Vdc)       60 Vdc Min.         Base Voltage to Turn Off (Vdc)       0.3 min         Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc)       6.0 min	Contact Resistance	0.15 Ω max.; 0.25 Ω max. afterlife at A / 28 Vdc					
Tontact Load Rating (AC)  100 mA / 115 Vac, 60 and 400 Hz (Case grounded)  10,000,000 cycles (typical) at low level 1,000,000 cycles (typical) at 0.5 A / 28 Vdc resistive 100,000 cycles min. at all other loads specified above  Contact Overload Rating  2 A / 28 Vdc Resistive (100 cycles min.)  Coil Operating Power  200 mW typical at nominal rated voltage  Contact Carry Rating  Contact Factory  Operate Time  6.0 msec max. at nominal rated coil voltage  Release Time  732: 3.0 ms max.  Intercontact Capacitance  1,000 MΩ min. between mutually isolated terminals  Dielectric Strength  350 Vrms (60 Hz) @ atmospheric pressure  Negative Coil Transient (Vdc)  Diode P.I.V. (Vdc)  60 Vdc Min.  Base Voltage to Turn Off (Vdc)  Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc)  6.0 min	Contact Load Rating (DC)	Inductive: 200 mA/ 28 Vdc (320mH) Lamp: 100 mA / 28 Vdc (320mH)					
Contact Life Ratings       1,000,000 cycles (typical) at 0.5 A / 28 Vdc resistive 100,000 cycles min. at all other loads specified above         Contact Overload Rating       2 A / 28 Vdc Resistive (100 cycles min.)         Coil Operating Power       200 mW typical at nominal rated voltage         Contact Carry Rating       Contact Factory         Operate Time       6.0 msec max. at nominal rated coil voltage         Release Time       732: 3.0 ms max.       732D, 732TN: 7.5 ms max.         Intercontact Capacitance       0.4 pf typical         Insulation Resistance       1,000 MΩ min. between mutually isolated terminals         Dielectric Strength       350 Vrms (60 Hz) @ atmospheric pressure         Negative Coil Transient (Vdc)       2.0 Vdc Max.         Diode P.I.V. (Vdc)       60 Vdc Min.         Base Voltage to Turn Off (Vdc)       0.3 min         TageTN Transistor Characteristics	Contact Load Rating (AC)						
Coil Operating Power       200 mW typical at nominal rated voltage         Contact Carry Rating       Contact Factory         Operate Time       6.0 msec max. at nominal rated coil voltage         Release Time       732: 3.0 ms max.       732D, 732TN: 7.5 ms max.         Intercontact Capacitance       0.4 pf typical         Insulation Resistance       1,000 MΩ min. between mutually isolated terminals         Dielectric Strength       350 Vrms (60 Hz) @ atmospheric pressure         Negative Coil Transient (Vdc)       2.0 Vdc Max.         Diode P.I.V. (Vdc)       60 Vdc Min.         Base Voltage to Turn Off (Vdc)       0.3 min         T32TN Transistor Characteristics       Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc)       6.0 min	Contact Life Ratings	1,000,000 cycles (typical) at 0.5 A / 28 Vdc resistive					
Contact Carry Rating       Contact Factory         Operate Time       6.0 msec max. at nominal rated coil voltage         Release Time       732: 3.0 ms max.       732D, 732TN: 7.5 ms max.         Intercontact Capacitance       0.4 pf typical         Insulation Resistance       1,000 MΩ min. between mutually isolated terminals         Dielectric Strength       350 Vrms (60 Hz) @ atmospheric pressure         Negative Coil Transient (Vdc)       2.0 Vdc Max.         Diode P.I.V. (Vdc)       60 Vdc Min.         Base Voltage to Turn Off (Vdc)       0.3 min         T32TN Transistor Characteristics       Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc)       6.0 min	Contact Overload Rating	2 A / 28 Vdc Resistive (100 cycles min.)					
Operate Time       6.0 msec max. at nominal rated coil voltage         Release Time       732: 3.0 ms max.       732D, 732TN: 7.5 ms max.         Intercontact Capacitance       0.4 pf typical         Insulation Resistance       1,000 MΩ min. between mutually isolated terminals         Dielectric Strength       350 Vrms (60 Hz) @ atmospheric pressure         Negative Coil Transient (Vdc)       2.0 Vdc Max.         Diode P.I.V. (Vdc)       60 Vdc Min.         T32TN Transistor Characteristics       Base Voltage to Turn Off (Vdc)       0.3 min         Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc)       6.0 min	Coil Operating Power	200 mW typical at nominal rated voltage					
Release Time       732: 3.0 ms max.       732D, 732TN: 7.5 ms max.         Intercontact Capacitance       0.4 pf typical         Insulation Resistance       1,000 MΩ min. between mutually isolated terminals         Dielectric Strength       350 Vrms (60 Hz) @ atmospheric pressure         Negative Coil Transient (Vdc)       2.0 Vdc Max.         Diode P.I.V. (Vdc)       60 Vdc Min.         Base Voltage to Turn Off (Vdc)       0.3 min         Characteristics	Contact Carry Rating	Contact Factory					
Intercontact Capacitance       0.4 pf typical         Insulation Resistance       1,000 MΩ min. between mutually isolated terminals         Dielectric Strength       350 Vrms (60 Hz) @ atmospheric pressure         Negative Coil Transient (Vdc)       2.0 Vdc Max.         Diode P.I.V. (Vdc)       60 Vdc Min.         Base Voltage to Turn Off (Vdc)       0.3 min         T32TN Transistor Characteristics	Operate Time	6.0 msec max. at nominal rated coil voltage					
Insulation Resistance       1,000 MΩ min. between mutually isolated terminals         Dielectric Strength       350 Vrms (60 Hz) @ atmospheric pressure         Negative Coil Transient (Vdc)       2.0 Vdc Max.         Diode P.I.V. (Vdc)       60 Vdc Min.         Base Voltage to Turn Off (Vdc)       0.3 min         T732TN Transistor Characteristics         Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc)       6.0 min	Release Time	732: 3.0 ms max. 732D, 732TN: 7.5 ms max.					
Dielectric Strength       350 Vrms (60 Hz) @ atmospheric pressure         Negative Coil Transient (Vdc)       2.0 Vdc Max.         Diode P.I.V. (Vdc)       60 Vdc Min.         Base Voltage to Turn Off (Vdc)       0.3 min         T32TN Transistor Characteristics       Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc)       6.0 min	Intercontact Capacitance	0.4 pf typical					
Negative Coil Transient (Vdc)         2.0 Vdc Max.           Diode P.I.V. (Vdc)         60 Vdc Min.           Base Voltage to Turn Off (Vdc)         0.3 min           732TN Transistor Characteristics           Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc)         6.0 min	Insulation Resistance	1,000 MΩ min. between mutually isolated terminals					
Diode P.I.V. (Vdc)   60 Vdc Min.	Dielectric Strength	350 Vrms (60 Hz) @ atmospheric pressure					
732TN Transistor Characteristics  Base Voltage to Turn Off (Vdc)  Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc)  0.3 min  6.0 min	Negative Coil Transient (Vdc)	2.0 Vdc Max.					
732TN Transistor Characteristics Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc) 6.0 min	Diode P.I.V. (Vdc)	60 Vdc Min.					
Characteristics Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc) 6.0 min		Base Voltage to Turn Off (Vdc)		0.3 min			
		Emitter-Base breakdown Voltage (BV <sub>EBO</sub> ) (Vdc)		6.0 min			
- · OBO· · ·		Collector-Base breakdown Voltage (BV <sub>CBO</sub> ) (Vdc)		60 min			

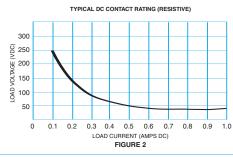
### **DETAILED ELECTRICAL SPECIFICATIONS (@25°C)**

BASE PART NUMBERS (732, 732D, 732TN)		732-5 732D-5 732TN-5	732-6 732D-6 732TN-6	732-9 732D-9 732TN-9	732-12 732D-12 732TN-12	732-18 732D-18 732TN-18	732-26 732D-26 732TN-26
Coil Voltage	Nom.	5.0	6.0	9.0	12.0	18.0	26.5
Con voitage	Max.	7.5	10.0	15.0	20.0	30.0	40.0
Coil Resistance (Ohms ±20%)		100	200	400	850	1600	3300
Pick-up Voltage (Vdc, Max.) Pulse Operation		3.5	4.5	6.8	9.0	13.5	18.0
732TN Base Current to Turn On (mAdc, min.)		1.5	1.00	0.75	0.47	0.38	0.24



.5 1.0

**PERFORMANCE CURVES (Note 2)** 



### GENERAL NOTES

- Relay contacts will exhibit no chatter in excess of 10 µsec or transfer in excess of 1 µsec.

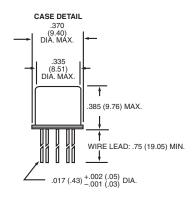
  2. "Typical" characteristics are based on
- available data and are best estimates. No on-going verification tests are performed.
  3. Unless otherwise specified, parameters
- are initial values.

  4. Relays can be supplied with a spacer pad. See appendix.

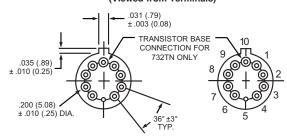
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### SERIES 732 OUTLINE DIMENSIONS

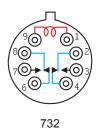


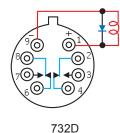
## TERMINAL LOCATIONS AND PIN NUMBERING (REF. ONLY) (Viewed from Terminals)

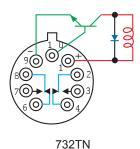


(Viewed From Terminals)

#### **SCHEMATIC DIAGRAMS**



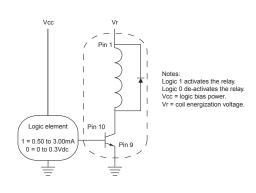




#### NOTES:

- 1. RELAY CONTACTS WILL EXHIBIT NO CHATTER IN EXCESS OF 10 MSEC OR TRANSFER IN EXCESS OF 1 MSEC.
- 2. "TYPICAL" CHARACTERISTICS ARE BASED ON AVAILABLE DATA AND ARE BEST ESTIMATES. NO ON-GOING VERIFICATION TESTS ARE PERFORMED.
- 3. UNLESS OTHERWISE SPECIFIED, PARAMETERS ARE INTIAL VALUES.
- 4. FOR REFERENCE ONLY. COIL RESISTANCE NOT DIRECTLY MEASURABLE ON 732TN RELAYS.
- 5. CIRCUIT IS TYPICAL FOR ALL SERIES 732TN. VALUES SHOWN ARE FOR 732TN-5 RELAY AND APPLY FOR FULL TEMPERATURE RANGE.LIMIT BASE-EMITTER CURRENT TO 15 MADC.
- 6. UNLESS OTHERWISE SPECIFIED, RELAYS WILL BE SUPPLIED WITH EITHER GOLD-PLATED OR SOLDER-COATED LEADS.
- 7. THE SLASH AND CHARACTERS APPEARING AFTER THE SLASH ARE NOT MARKED ON THE RELAY.

### TYPICAL LOGIC INTERFACE



# **APPENDIX: Spacer Pads**

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
		ER412, ER412D, ER412DD	.295 (7.49)
Ø.150 [3.81]   (REF)	Dim H MAX	712, 712D, 712TN, RF300, RF310, RF320 RF700, RF703	.300 (7.62)
		ER420, ER420D, ER420DD, 421, ER421D, ER421DD, ER422, ER422D, ER422DD, 722, 722D, RF341	.305 (7.75)
		ER431T, ER432T, ER432, ER432D, ER432DD	.400 (10.16)
		732, 732D, 732TN, RF303, RF313, RF323	.410 (10.41)
"M4" Pad for TO-5		RF312, RF332 SI800, SI803	.350 (8.89)
	Dim H MAX	ER411, ER411D, ER411DD, ER411T	.295 (7.49)
		ER431, ER431D, ER431DD	.400 (10.16)
(000)		RF311	.300 (7.62)
"M4" Pad for TO-5		RF331	.410 (10.41)
	Dim H MAX	172, 172D	.305 (7.75)
0 0 0		ER114, ER114D, ER114DD, J114, J114D, J114DD	.300 (7.62)
		ER134, ER134D, ER134DD, J134, J134D, J134DD	.400 (10.16)
		RF100	.315 (8.00)
"M4" Pad for Centigrid®		RF103	.420 (10.67)
.156 [3.96]   (REF)	Dim H MAX	122C, A152	.320 (8.13)
000		ER116C, J116C	.300 (7.62)
256 [6.5] (REF)		ER136C, J136C	.400 (10.16)
		RF180	.325 (8.25)
"M9" Pad for Centigrid®		A150	.305 (7.75)

### Notes:

- 1. Spacer pad material: Polyester film.
- To specify an "M4" or "M9" spacer pad, refer to the mounting variants portion of the part numbering example in the applicable datasheet.
- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is ± .010" (.25 mm).
- 5. Add 10 m $\Omega$  to the contact resistance shown in the datasheet.
- 6. Add 0.01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.

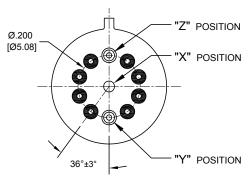
### **APPENDIX: Spreader Pads**

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
.100	T	ER411T, J411T, ER412, ER412D ER412DD, J412, J412D, J412DD ER412T, J412T	.388 (9.86)
[2.54]	Dim H	712, 712D, 712TN	.393 (9.99)
.150 [3.81] [7.62]	MAX .014 [0.36] (REF)	ER431T, J431T, ER432, ER432D ER432DD, J432, J432D, J432DD ER432T, J432T	.493 (12.52)
<b>⊕</b> .100		732, 732D, 732TN	.503 (12.78)
"M" Pad <u>5</u> / <u>6</u> /	.370 [9.4] MIN	ER420, J420, ER420D, J420D ER420DD, J420DD, ER421, J421 ER421D, J421D, ER421DD J422D, ER422DD, J422DD, 722	.398 (10.11)
390 [9.91] SQ .100 [2.54]	90 [9.91]	ER411T ER412, ER412D, ER412DD J412, J412D, J412DD	.441 (11.20)
100		712, 712D	.451 (11.46)
300 (7.62)		ER421, ER421D, ER421DD 722, 732D	.451 (11.46)
.300 [3.81]		ER431T ER432, ER432D, ER432DD	.546 (13.87)
"M2" Pad <u>7</u> / <u>8</u> /		732, 732D	.556 (14.12)
.370 [9.4] MAX SQ	T	ER411, ER411D, ER411DD, ER411TX ER412X, ER412DX, ER412DDX ER412TX	.388 (9.86)
.100 [2.54]	Dim H MAX	712X, 712DX, 712TNX	.393 (9.99)
.150 [3.81] [7.62]		ER420X, ER420DX, ER420DDX ER421X, ER421DX, ER421DDX ER422X, ER422DX ER422DDX, 722X, 722DDX	.398 (10.11)
(2.54) (5.08)		ER431, ER431D, ER431DD ER431TX ER432X, ER432DX, ER432DDX ER432TX	.493 (12.52)
"M3" Pad <u>5</u> / <u>6</u> / <u>9</u> /	<u>,                                      </u>	732X, 732DX, 732TNX	.503 (12.78)

### Notes:

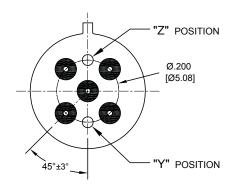
- 1. Spreader pad material: Diallyl Phthalate.
- 2. To specify an "M", "M2" or "M3" spreader pad, refer to the mounting variants portion of the part number example in the applicable datasheet.
- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is ± .010" (0.25 mm).
- $\underline{5}$ /. Add 25 m $\Omega$  to the contact resistance shown in the datasheet.
- 6/. Add .01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.
- $\underline{7}$ /. Add 50 m $\Omega$  to the contact resistance shown in the datasheet.
- 8/. Add 0.025 oz (0.71 g) to the weight of the relay assembly shown in the datasheet.
- 9/. M3 pad to be used only when the relay has a center pin (e.g. ER411M3-12A, 722XM3-26.)

### **APPENDIX: Ground Pin Positions**



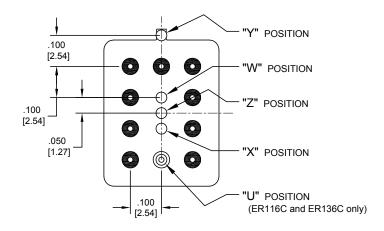
### TO-5 Relays:

ER411T, ER412, ER412T, ER420, ER421, ER422, ER431T, ER432, ER432T, 712, 712TN, 400H, 400K, 400V, RF300, RF303, RF341, RF312, RF332, RF310, RF313, RF320, RF323, SI800, SI803, RF700, RF703



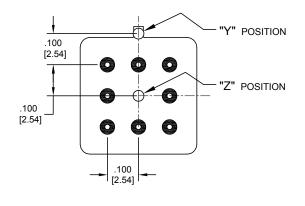
### TO-5 Relays:

ER411, ER431, RF311, RF331



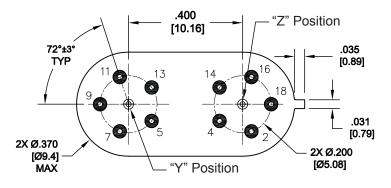
### Centigrid® Relays:

RF180, ER116C, 122C, ER136C



### Centigrid® Relays:

RF100, RF103, ER114, ER134, 172



# Loopback Relays: LB363

- NOTES
  - 1. Terminal views shown
  - 2. Dimensions are in inches (mm)
  - 3. Tolerances: ± .010 (±.25) unless otherwise specified
  - 4. Ground pin positions are within .015 (0.38) dia. of true position
  - 5. Ground pin head dia., 0.035 (0.89) ref: height 0.010 (0.25) ref.
  - 6. Lead dia. 0.017 (0.43) nom.
- O Indicates ground pin position
- Indicates glass insulated lead position
- Indicates ground pin or lead position depending on relay type